

TOSHIBA

MT6C04AE

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

MT6C04AE

VHF~UHF BAND LOW NOISE AMPLIFIER APPLICATIONS

Unit in mm

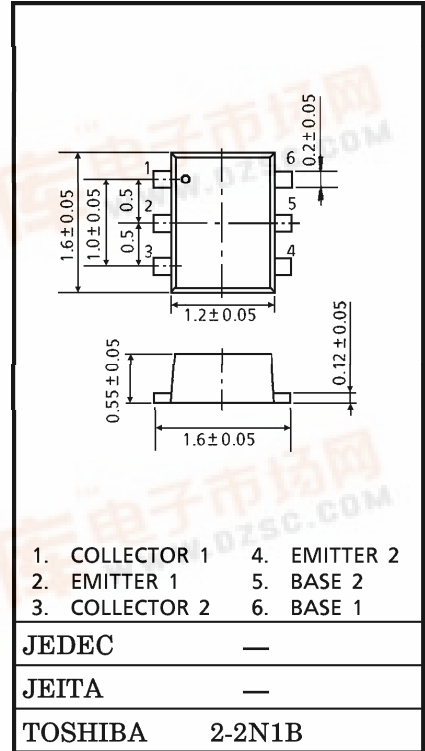
- Two devices are built in to the super-thin and extreme super mini (6 pins) package : ES6

MOUNTED DEVICES

| | |
|---|----------------------|
| | Q1 / Q2 : SSM (TESM) |
| Three-pins (SSM / TESM) mold products are corresponded. | MT3S04AS (MT3S04AT) |

MAXIMUM RATINGS (Ta = 25°C)

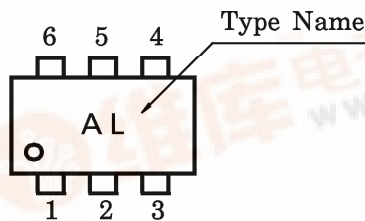
| CHARACTERISTIC | SYMBOL | Q1 / Q2 | UNIT |
|-----------------------------|----------------------------|---------|------|
| Collector-Base Voltage | V _{CB0} | 10 | V |
| Collector-Emitter Voltage | V _{CEO} | 5 | V |
| Emitter-Base Voltage | V _{EB0} | 2 | V |
| Collector Current | I _C | 40 | mA |
| Base Current | I _B | 10 | mA |
| Collector Power Dissipation | P _C (Note 1) | 100 | mW |
| Junction Temperature | T _j | 125 | °C |
| Storage Temperature Range | T _{stg} | -55~125 | °C |



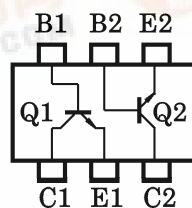
Weight : 0.003 g

(Note 1) : Total power dissipation of Q1 and Q2.

MARKING



PIN ASSIGNMENT (TOP VIEW)



ELECTRICAL CHARACTERISTICS Q1/Q2 (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|------------------------------|------------------|--|------|------|------|---------------|
| Collector Cut-off Current | I_{CBO} | $V_{CB} = 5\text{ V}, I_E = 0$ | — | — | 0.1 | μA |
| Emitter Cut-off Current | I_{EBO} | $V_{EB} = 1\text{ V}, I_C = 0$ | — | — | 1 | μA |
| DC Current Gain | h_{FE} | $V_{CE} = 1\text{ V}, I_C = 5\text{ mA}$ | 80 | — | 160 | — |
| Transition Frequency | $f_T(1)$ | $V_{CE} = 1\text{ V}, I_C = 5\text{ mA}$ | 2 | 4.5 | — | GHz |
| | $f_T(2)$ | $V_{CE} = 3\text{ V}, I_C = 7\text{ mA}$ | 5 | 7 | — | GHz |
| Insertion Gain | $ S_{21e} ^2(1)$ | $V_{CE} = 1\text{ V}, I_C = 5\text{ mA},$ $f = 1\text{ GHz}$ | — | 8.5 | — | dB |
| | $ S_{21e} ^2(2)$ | $V_{CE} = 3\text{ V}, I_C = 20\text{ mA},$ $f = 1\text{ GHz}$ | 7.5 | 11 | — | dB |
| Noise Figure | NF (1) | $V_{CE} = 1\text{ V}, I_C = 5\text{ mA},$ $f = 1\text{ GHz}$ | — | 1.3 | 2.2 | dB |
| | NF (2) | $V_{CE} = 3\text{ V}, I_C = 7\text{ mA},$ $f = 1\text{ GHz}$ | — | 1.2 | 2 | dB |
| Reverse Transfer Capacitance | C_{re} | $V_{CB} = 1\text{ V}, I_E = 0,$ $f = 1\text{ MHz (Note 2)}$ | — | 0.9 | 1.25 | pF |

(Note 2) : C_{re} is measured by 3 terminal method with capacitance bridge.

HANDLING PRECAUTION

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

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